

Revision 0.90

SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser



General Product Information

Product	Application
767 nm DFB Laser with hermetic Butterfly Housing	Spectroscopy
Monitor Diode, Thermoelectric Cooler and Thermistor	Metrology
Collimated beam	K Spectroscopy (Variant0005)
ROHS compliant	



Absolute Maximum Ratings

Parameter	Symbol	Unit	min	typ	max
Storage Temperature	T_S	°C	-40		85
Operational Temperature at Case	T_{C}	°C	-40		85
Operational Temperature at Laser Chip	T_{LD}	°C	10		50
Forward Current	I_{F}	mA			130
Reverse Voltage	V_R	V			2
Output Power	P_{opt}	mW			60
TEC Current	I _{TEC}	Α			1.8
TEC Voltage	V_{TEC}	V			2.8

Stress in excess of the Absolute Maximum Ratings can cause permanent damage to the device.

Recommended Operational Conditions

Parameter	Symbol	Unit	min	typ	max
Operational Temperature at Case	T _C	°C	-20		65
Operational Temperature at Laser Chip	T_{LD}	°C	15		35
Forward Current	I _F	mA			120
Output Power	P_{opt}	mW	10		50

Measurement Conditions / Comments	
measured by integrated Thermistor	

Characteristics at T_{LD} = 25 °C at Begin Of Life

Parameter	Symbol	Unit	min	typ	max
Center Wavelength	λ_{C}	nm	766	767	768
Tuning Range by Temperature	$\Delta \lambda_{\text{T}}$	nm		1.2	
Spectral Width (FWHM)	$\Delta \nu$	MHz		2	
Temperature Coefficient of Wavelength	dλ / dT	nm / K		0.06	
Current Coefficient of Wavelength	dλ / dl	nm / mA		0.003	
Output Power @ I _F : 120 mA	P_{opt}	mW	50		

Measurement Conditions / Comments
see images on page 4
see also "Mode-hop free Operating Range" (p.2)

fax +49. 30. 6392 4529



Revision 0.90

SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser



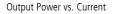
Characteristics at T _{amb}	, 25 °C at E	3egin C	of Life		cont'd
Parameter	Symbol	Unit	min	typ	max
Slope Efficiency	η	W/A	0.6	0.9	1.1
Threshold Current	I _{th}	mA			70
Divergence parallel (1/e²)	$\Theta_{ }$	0		0.1	
Divergence perpendicular (1/e²)	Θ_{\perp}	0		0.1	
Beam Diameter (1/e²)	d	mm		1.0	1.2
Beam Diameter (1/e²)	d_\perp	mm		0.8	1.2
Degree of Polarization	DOP	%		90	
Sidemode Supression Ratio	SMSR	dB	30	50	
Mode-hop free Operating Range (SMSR >	- 30 dB)				
Variant 0	T_LD	° C		25	
	P_{opt}	mW		50	
Variant 2	T_LD	° C	15		35
	P_{opt}	mW	10		50
Variant 5	λ_{C}	nm		766.70	
	P_{opt}	mW		50	

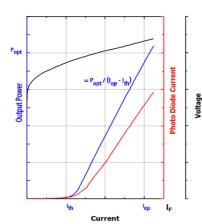
Measurement Conditions / Comments
parallel to the base plate of the housing (see p. 3)
perpendicular to base plate of the housing (see p. 3)
parallel to the base plate of the housing (see p. 3)
perpendicular to base plate of the housing (see p. 3) $P_{opt} = 50$ mW; E field perpendicular to the base plate
P _{opt} = 50 mW
see order code scheme on p. 5
wavelength reached within $T_{LD} = 15$ ° and 35° C

Monitor Diode					
Parameter	Symbol	Unit	min	typ	max
Monitor Detector Responsivity	I _{mon} /P _{opt}	μΑ/mW	2		40

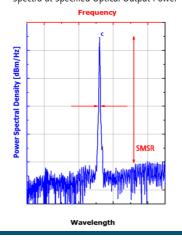
Measurement Conditions / Comments
Reverse Voltage $U_{R \; MD} = 5 \; V$

Typical Measurement Results





Spectra at Specified Optical Output Power



Performance figures, data and any illustrative material provided in this specification are typical and must be specifically confirmed in writing by eagleyard Photonics before they become applicable to any particular order or contract. In accordance with the eagleyard Photonics policy of continuous improvement specifications may change without notice.



Revision 0.90

SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser



Thermoelectric Cooler

Parameter	Symbol	Unit	min	typ	max
Current	I _{TEC}	А		0.4	
Voltage	U_TEC	V		0.8	
Power Dissipation (total loss at case)	P _{loss}	W		0.4	
Temperature Difference	ΔΤ	K			50

Measurement C	Conditions / Comments	
$P_{opt} = 50 \text{ mW},$	$\Delta T = 20 \text{ K}$	
$P_{opt} = 50 \text{ mW},$	$\Delta T = 20 \text{ K}$	
$P_{opt} = 50 \text{ mW},$	$\Delta T = 20 \text{ K}$	
$P_{opt} = 50 \text{ mW},$	$\Delta T = I T_{case} - T_{LD} I$	

Thermistor (Standard NTC Type)

Parameter	Symbol	Unit	min	typ	max
Resistance	R	kΩ		10	
Beta Coefficient	β			3892	
Steinhart & Hart Coefficient	А			1.1293 x 10 ⁻	3
Steinhart & Hart Coefficient	В		:	2.3410 x 10 ⁻	4
Steinhart & Hart Coefficient	C		8	8.7755 x 10 ⁻	8

Measurement Conditions / Comments			
T = 25° C			
$R_1 / R_2 = e^{\beta (1/T_1 \cdot 1/T_2)} $ at $T=0^\circ \dots 50^\circ C$			
$1/T = A + B(\ln R) + C(\ln R)^3$			
T: temperature in Kelvin			
R: resistance at T im Ohm			



Revision 0.90

SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser



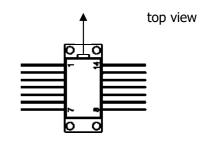
Package Dimensions

Parameter	Symbol	Unit	min	typ	max
Emission Plane	h _{EP}	mm		4.9	

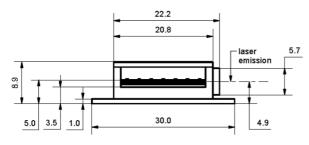
Measurement Conditions / Comments

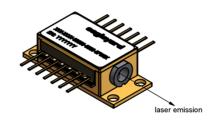
Package Pinout

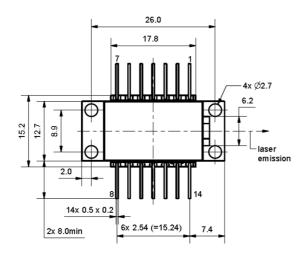
1	Thermoelectric Cooler (+)	14	Thermoelectric Cooler (-)
2	Thermistor	13	Case
3	Photodiode (Anode)	12	not connected
4	Photodiode (Cathode)	11	Laser Diode (Cathode)
5	Thermistor	10	Laser Diode (Anode)
6	not connected	9	not connected
7	not connected	8	not connected



Package Drawings







AIZ-15-0729-0947A





Revision 0.90

SINGLE FREQUENCY LASER DIODES Distributed Feedback Laser



Order Code Scheme

x is a wildcard representing the different variants of the laser. Please select.

Mode-hop free Operating Range (Minimum Side Mode Suppression Ratio > 30 dB)

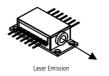
T _{LD} = 25 ° C	$P_{opt} = 50 \text{ mW}$	(Variant 0)	
T _{LD} = 15 35 ° C;	$P_{opt} = \ 10 \ \dots \ 50 \ mW$	(Variant 2)	
$\lambda_c\!=\!766.70\;\text{nm}$	$P_{opt} = 50 \text{ mW}$	(Variant 5)	

EYP-DFB-0767-00050-1500-BFW01- 0 0 0 x

(0
į.	2
·	5

Unpacking, Installation and Laser Safety

Unpacking the laser diodes should only be done at electrostatic safe workstations (EPA). Though protection against electro static discharge (ESD) is implemented in the laser package, charges may occur at surfaces. Please store this product in its original package at a dry, clean place until final use. During device installation, ESD protection has to be maintained.





The DFB diode type is known to be sensitive against optical feedback, so an optical isolator may be required in some cases. Operating at moderate temperatures on a proper metal heat sinks will contribute to stable operation and a long lifetime of the diode.

The laser emission from this diode is close to the invisible infrared region of the electromagnetic spectrum. Avoid direct and/or indirect exposure to the free running beam. Collimating the free running beam with optics as common in optical instruments will increase threat to the human eye.

Each laser diode will come with an individual test protocol verifying the parameters given in this document.









Ordering Information:



800 Village Walk #316 Guilford, CT 06437 Ph: 203-401-8093

Email orders to: sales@xsoptix.com
Fax orders to: 800-878-7282

DNV-GL